



<b>AMENDMENT TRANSMITTAL LETTER</b>				Docket No. M4065.0210/P210-A	
Application No. 10/002,176	Filing Date December 5, 2001	Examiner Vikki Trinh	Art Unit 2814		
Applicant(s): Yang, et al.					
Invention: IMPROVED MEMORY CELL CAPACITOR STRUCTURE AND METHOD OF FORMATION					
<b>TO THE COMMISSIONER FOR PATENTS</b>					
Transmitted herewith is an amendment in the above-identified application.					
The fee has been calculated and is transmitted as shown below.					
<b>CLAIMS AS AMENDED</b>					
	Claims Remaining After Amendment	Highest Number Previously Paid	Number Extra Claims Present	Rate	
Total Claims	37	- 65 =	0	x	
Independent Claims	2	- 3 =	0	x	
Multiple Dependent Claims (check if applicable) <input type="checkbox"/>					
Other fee (please specify):					
<b>TOTAL ADDITIONAL FEE FOR THIS AMENDMENT:</b>					
<div style="display: flex; justify-content: space-between;"><div><input checked="" type="checkbox"/> Large Entity</div><div><input type="checkbox"/> Small Entity</div></div> <div style="margin-top: 5px;"><input checked="" type="checkbox"/> No additional fee is required for this amendment.</div> <div style="margin-top: 5px;"><input type="checkbox"/> Please charge Deposit Account No. _____ in the amount of \$ _____ A duplicate copy of this sheet is enclosed.</div> <div style="margin-top: 5px;"><input type="checkbox"/> A check in the amount of \$ _____ to cover the filing fee is enclosed.</div> <div style="margin-top: 5px;"><input type="checkbox"/> Payment by credit card. Form PTO-2038 is attached.</div> <div style="margin-top: 5px;"><input type="checkbox"/> The Commissioner is hereby authorized to charge and credit Deposit Account No. <u>04-1073</u> as described below. A duplicate copy of this sheet is enclosed.</div> <div style="margin-top: 5px;"><input type="checkbox"/> Credit any overpayment.</div> <div style="margin-top: 5px;"><input type="checkbox"/> Charge any additional filing or application processing fees required under 37 CFR 1.16 and 1.17.</div>					
Thomas J. D'Amico Attorney Reg. No.: 28,371 DICKSTEIN SHAPIRO MORIN & OSHINSKY LLP 2101 L Street NW Washington, DC 20037-1526 (202) 828-2232				Dated: <u>July 21, 2004</u>	



AF/2814  
IFW

Docket No.: M4065.0210/P210-A  
(PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:  
Sam Yang, et al.

Examiner: Vikki Trinh

Application No.: 10/002,176

Art Unit: 2814

Filed: December 5, 2001

For: IMPROVED MEMORY CELL CAPACITOR  
STRUCTURE AND METHOD OF  
FORMATION

**AMENDMENT AFTER FINAL ACTION (37 C.F.R. SECTION 1.116)**

Commissioner for Patents  
MS: AF  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

This paper is in response to the Office Action dated June 1, 2004. Please amend the above-identified U.S. patent application as follows:

**Amendment to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks** begin on page 10 of this paper.